■1.25Gbps / 2.50Gbps Hybrids

GaAs Photodetectors / Transimpedance Amplifiers

FCI-H125/250G-GaAs-100 series with active area sizes of 100µm is a compact integration of our high speed GaAs photodetector with a wide dynamic range transimpedance amplifier. Combining the detector with the TIA in a hermetically sealed 4 pin TO-46 or TO-52 package provides ideal conditions for high speed signal amplification. Low capacitance, low dark current and high responsivity from 650nm to 860nm make these devices ideal for high-bit rate receivers used in LAN, MAN, and other high speed communication systems. TO packages come standard with a lensed cap to enhance coupling efficiency, or with a broadband double sided AR coated flat window. The FCI-H125/250G-GaAs-100 series is also offered with FC, SC, ST and SMA receptacles.



APPLICATIONS

- High Speed Optical Communications
- Gigabit Ethernet
- Fibre Channel
- ATM

FEATURES

- GaAs Photodector / Low Noise Transimpedance Amplifier
- High Bandwidth / Wide Dynamic Range
- Hermetically Sealed TO-46 Can
- Single +3.3V to +5V Power Supply
- SONET OC-48 / SDH STM-16 Spectral Range 650nm to 850nm
 - Differential Output

Absolute Maximum Ratings					
PARAMETERS	SYMBOL	MIN	MAX	UNITS	
Storage Temperature	T _{stg}	-40	+125	°C	
Operating Temperature	T _{op}	0	+75	°C	
Supply Voltage	V _{cc}	0	+6	V	
Input Optical Power	P _{IN}		+5	dBm	

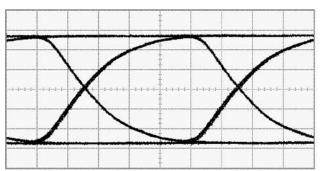
Electro-Optical Characteristics		$ extsf{T}_{A} extsf{=}23^{\circ} extsf{C}, extsf{ Vcc=+3.3V}, extsf{ 850nm, 100}\Omega extsf{ Differential AC Load}$							
PARAMETERS	SYMBOL	CONDITIONS	FCI-H125G-GaAs-100		FCI-H250G-GaAs-100			UNITS	
PARAMETERS	STMBUL	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIIS
Supply Voltage	V _{CC}		+3		+5.5	+3		+5.5	V
Supply Current	I _{CC}	*T _A = 0 to 70°C		26	*55		35	*65	mA
Active Area Diameter	AA_{ϕ}			100			100		μm
Operating Wavelength	λ		650		860	650		860	nm
Responsivity	R_{λ}	-17dBm, Differential	1000	1700		1000	1650		V/W
Transimpedance		-17dBm, Differential		2800			2800		Ω
Sensitivity	S	BER 10 ⁻¹⁰ , PRBS2 ⁷ -1	-22	-26		-19	-22		dBm
Optical Overload			0			0			dBm
Bandwidth	BW	-3dB, Small Signal		900			1700		MHz
Low Frequency Cutoff		-3dB		45			30		kHz
Differential Output Voltage	V _{OUT, P-P}	-3dBm	180	250	420	200	400	600	mV _{P-P}
Output Impedance			47	50	53	47	50	53	Ω
Transimpedance Linear Range		<5%	50			65			μW _{P-P}

Use AC coupling and differential 100Ω load for the best high-speed performance. Devices are not intended to drive DC coupled, 50Ω grounded load.

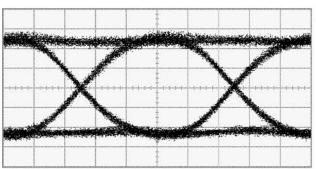
■1.25Gbps / 2.50Gbps Hybrids

GaAs Photodetectors / Transimpedance Amplifiers

FCI-H125G-GaAs-100

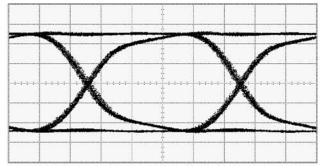


50mV / div, 160ps / div, -6dBm, 850nm, PRBS27-1, Diff.

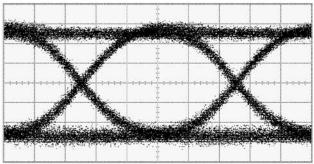


10mV / div, 160ps / div, -17dBm, 850nm, PRBS27-1, Diff.

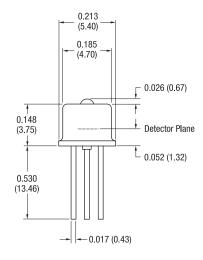
FCI-H250G-GaAs-100



80mV / div, 80ps / div, -6dBm, 850nm, PRBS27-1, Diff.



10mV / div, 80ps / div, -17dBm, 850nm, PRBS27-1, Diff.

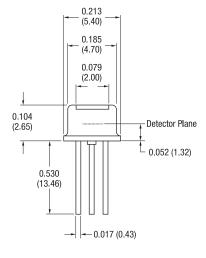




Bottom View



Pin Circle Diameter = 0.100 (2.54)





Bottom View

PINOUT 1 D_{out} $2 V_{\rm CC}$

3 D_{out} 4 GND

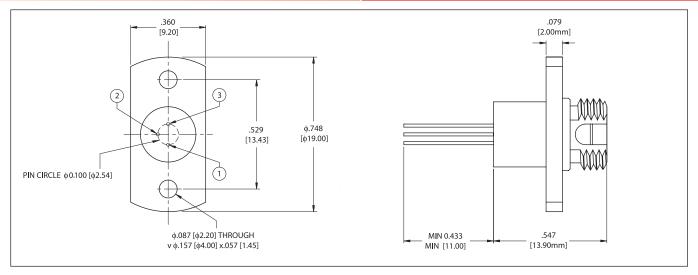
Pin Circle Diameter = 0.100 (2.54)

 $V_{\rm CC}$ $\mathsf{D}_{\mathsf{out}}$ $\overline{\mathrm{D}_{\mathrm{out}}}$ GND

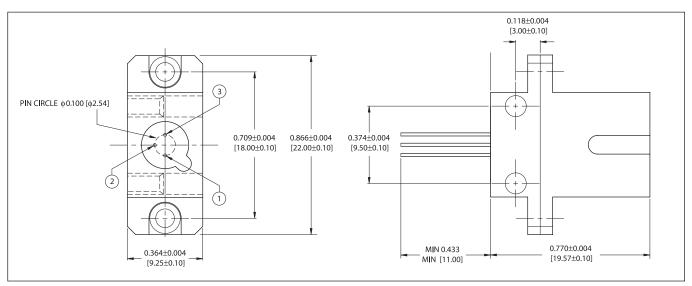
Notes:

- All units in inches (mm).
- All tolerances: 0.005 (0.125).
- Please specify when ordering the flat window or lens cap devices.
- The flat window devices have a double sided AR coated window at 850nm.
- The thickness of the flat window=0.008 (0.21).

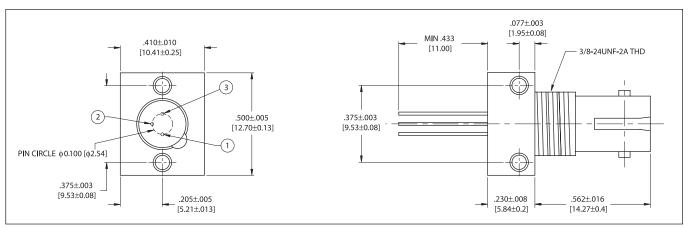
FC / SC / ST Receptacles Packages



FC Receptacles Package



SC Receptacles Package



ST Receptacles Package

 $Please \ note that \ all \ receptacle-associated \ photo-detectors \ carry \ an \ additional \ 0.45 dB \ insertion \ loss-that \ is \ 10\% \ loss \ to \ the$ incident signal power.

PIN#	FCI-HR-XXX	FCI-125G-XXXHR FCI-InGaAs-XXX
1	ANODE	CATHODE
2	CATHODE	CASE
3	CASE	ANODE